

CD4016B Types

CMOS Quad Bilateral Switch

For Transmission or Multiplexing of Analog or Digital Signals

High-Voltage Types (20-Volt Rating)

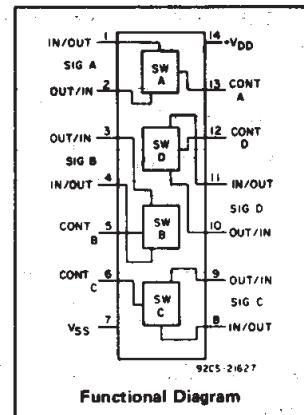
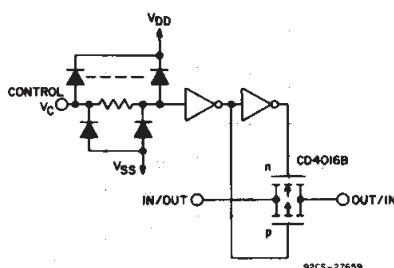
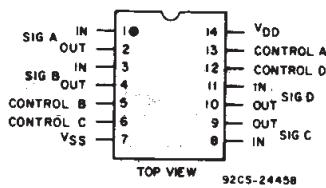
CD4016B Series types are quad bilateral switches intended for the transmission or multiplexing of analog or digital signals. Each of the four independent bilateral switches has a single control signal input which simultaneously biases both the p and n device in a given switch on or off.

The CD4016 "B" Series types are supplied in 14-lead hermetic dual-in-line ceramic packages (D and F suffixes), 14-lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).

Features:

- 20-V digital or ± 10 -V peak-to-peak switching
- 280- Ω typical on-state resistance for 15-V operation
- Switch on-state resistance matched to within 10 Ω typ. over 15-V signal-input range
- High on/off output-voltage ratio: 65 dB typ. @ $f_{IS} = 10$ kHz, $R_L = 10$ k Ω
- High degree of linearity: <0.5% distortion typ. @ $f_{IS} = 1$ kHz, $V_{IS} = 5$ V p-p, $V_{DD}-V_{SS} \geq 10$ V, $R_L = 10$ k Ω
- Extremely low off-state switch leakage resulting in very low offset current and high effective off-state resistance: 100 pA typ. @ $V_{DD}-V_{SS}=18$ V, $T_A=25^\circ C$
- Extremely high control input impedance (control circuit isolated from signal circuit: 10^{12} Ω typ.)
- Low crosstalk between switches: -50 dB typ. @ $f_{IS} = 0.9$ MHz, $R_L = 1$ k Ω
- Matched control-input to signal-output capacitance: Reduces output signal transients
- Frequency response, switch on = 40 MHz (typ.)
- 100% tested for quiescent current at 20 V
- Maximum control input current of 1 μA at 18 V over full package temperature range; 100 nA at 18 V at $25^\circ C$
- 5-V, 10-V, and 15-V parametric ratings
- Applications:**
 - Analog signal switching/multiplexing
 - Signal gating ■ Modulator
 - Squelch control ■ Demodulator
 - Chopper ■ Commutating switch
 - Digital signal switching/multiplexing
 - CMOS logic implementation
 - Analog-to-digital & digital-to-analog conversion
 - Digital control of frequency, impedance, phase, and analog-signal gain

Terminal Assignment



Schematic diagram - 1 of 4 identical sections.

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following range:

CHARACTERISTIC	LIMITS		UNITS
	Min.	Max.	
Supply Voltage Range (For $T_A =$ Full Package Temperature Range)	3	18	V

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V_{DD})

Voltages referenced to V_{SS} Terminal) -0.5V to +20V

INPUT VOLTAGE RANGE, ALL INPUTS -0.5V to V_{DD} +0.5V

DC INPUT CURRENT, ANY ONE INPUT ± 10 mA

POWER DISSIPATION PER PACKAGE (P_D):

For $T_A = -55^\circ C$ to $+100^\circ C$ 500mW

For $T_A = +100^\circ C$ to $+125^\circ C$ Derate Linearity at 12mW/ $^\circ C$ to 200mW

DEVICE DISSIPATION PER OUTPUT TRANSISTOR

FOR $T_A =$ FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW

OPERATING-TEMPERATURE RANGE (T_A) -55°C to $+125^\circ C$

STORAGE TEMPERATURE RANGE (T_{STG}) -65°C to $+150^\circ C$

LEAD TEMPERATURE (DURING SOLDERING):

At distance $1/16 \pm 1/32$ inch (1.59 \pm 0.79mm) from case for 10s max $+265^\circ C$

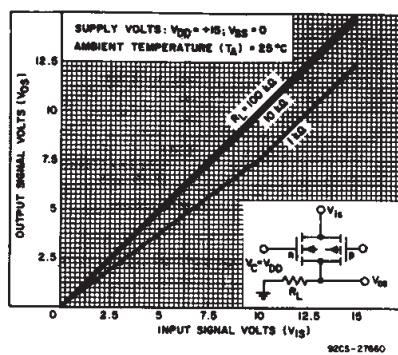


Fig. 1—Typ. on-state characteristics for 1 of 4 switches with $V_{DD} = +15$ V, $V_{SS} = 0$ V.

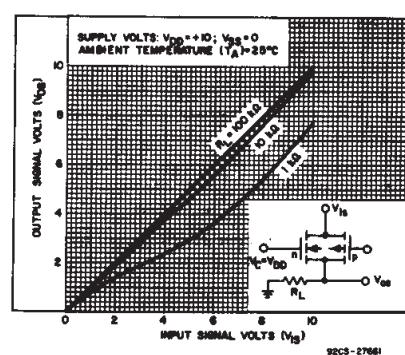


Fig. 2—Typ. on-state characteristics for 1 of 4 switches with $V_{DD} = +10$ V, $V_{SS} = 0$ V.

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ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TEST CONDITIONS		LIMITS AT INDICATED TEMPERATURES (°C)						UNITS	
			V_{IN} (V)	V_{DD} (V)	-55	-40	+85	+125	Typ.	
Quiescent Device Current, I_{DD}			0.5	5	0.25	0.25	7.5	7.5	0.01	0.25
			0.10	10	0.5	0.5	15	15	0.01	0.5
			0.15	15	1	1	30	30	0.01	1
			0.20	20	5	5	150	150	0.02	5
Signal Inputs (V_{IS}) and Output (V_{OS})										
On-State Resistance, r_{on} Max.		$V_C = V_{DD}$	$V_{IS} = V_{DD}$ or V_{SS}	10	600	610	840	960	—	660
		$R_L = 10\text{k}\Omega$	$V_{IS} = 4.75$ to 5.75V	10	1870	1900	2380	2600	—	2000
		Returned to $V_{DD} - V_{SS}$	$V_{IS} = V_{DD}$ or V_{SS}	15	360	370	520	600	—	400
		2	$V_{IS} = 7.25$ to 7.75V	15	775	790	1080	1230	—	850
Δ On-State Resistance Between Any 2 Switches, Δr_{on}		$R_L = 10\text{k}\Omega$, $V_C = V_{DD}$	5	—	—	—	—	15	—	—
			10	—	—	—	—	10	—	—
			15	—	—	—	—	5	—	—
Total Harmonic Distortion, THD	$V_C = V_{DD} = 5\text{V}$, $V_{SS} = -5\text{V}$, V_{IS} (p-p) = 5V (Sine wave centered on 0V) $R_L = 10\text{k}\Omega$, $f_{IS} = 1\text{kHz}$ sine wave	—	—	—	—	—	0.4	—	%	
-3dB Cutoff Frequency (Switch on)	$V_C = V_{DD} = 5\text{V}$, $V_{SS} = -5\text{V}$, V_{IS} (p-p) = 5V (Sine wave centered on 0V) $R_L = 1\text{k}\Omega$	—	—	—	—	—	40	—	MHz	
-50dB Feed-through Frequency (Switch off)	$V_C = V_{SS} = -5\text{V}$, V_{IS} (p-p) = 5V (Sine wave centered on 0V) $R_L = 1\text{k}\Omega$	—	—	—	—	—	1.25	—	MHz	
Input/Output Leakage Current (Switch off), I_{IS} Max.	$V_C = 0\text{V}$ $V_{IS} = 18\text{V}$, $V_{OS} = 0\text{V}$; $V_C = 0\text{V}$, $V_{OS} = 18\text{V}$	18	± 0.1	± 0.1	± 1	± 1	10^{-4}	± 0.1	μA	
-50 dB Crosstalk Frequency	$V_C(A) = V_{DD} = +5\text{V}$, $V_C(B) = V_{SS} = -5\text{V}$, $V_{IS}(A) = 5\text{V}$ p-p 50 Ω source $R_L = 1\text{k}\Omega$	—	—	—	—	—	0.9	—	MHz	
Propagation Delay (Signal Input to Signal Output) t_{pd}	$R_L = 200\text{k}\Omega$ $V_C = V_{DD}$, $V_{SS} = \text{GND}$, $C_L = 50\text{pF}$ V_{IS} = Square Wave 0 to V_{DD} $t_r, t_f = 20\text{ ns}$	5	—	—	—	—	40	100	ns	
Capacitance: Input, C_{IS}	$V_{DD} = +5\text{V}$	—	—	—	—	—	4	—	pF	
Output, C_{OS}	$V_C = V_{SS} = -5\text{V}$	—	—	—	—	—	4	—		
Feedthrough, C_{ios}		—	—	—	—	—	0.2	—		

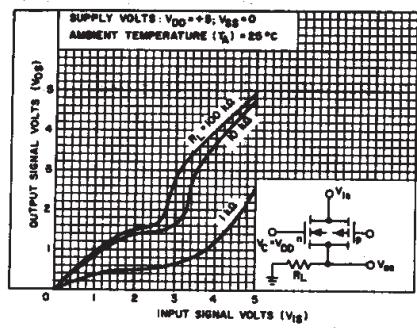


Fig. 3—Typ. on-state characteristics for 1 of 4 switches with $V_{DD} = +5\text{V}$, $V_{SS} = 0\text{V}$.

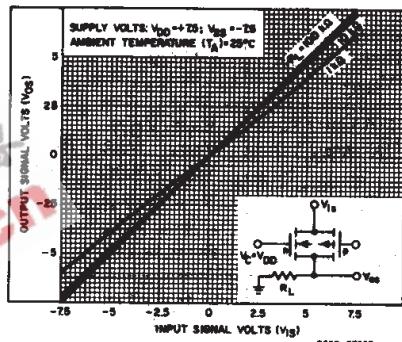


Fig. 4—Typ. on-state characteristics for 1 of 4 switches with $V_{DD} = +7.5\text{V}$, $V_{SS} = -7.5\text{V}$.

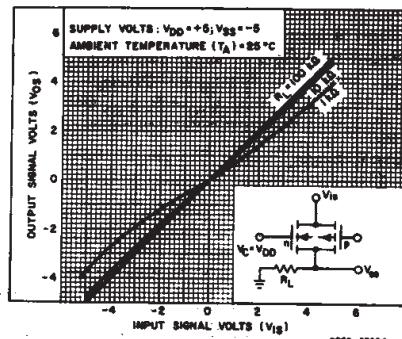


Fig. 5—Typ. on-state characteristics for 1 of 4 switches with $V_{DD} = +5\text{V}$, $V_{SS} = -5\text{V}$.

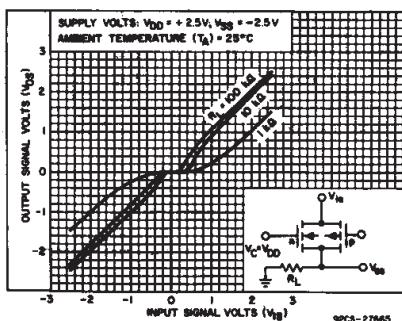


Fig. 6—Typ. on-state characteristics for 1 of 4 switches with $V_{DD} = +2.5\text{V}$, $V_{SS} = -2.5\text{V}$.

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ELECTRICAL CHARACTERISTICS (cont'd)

CHARACTERISTIC	TEST CONDITIONS	V_{DD} (V)	LIMITS AT INDICATED TEMPERATURES ($^{\circ}\text{C}$)						UNITS
			-55	-40	+85	+125	Typ.	Max.	
Control (V_C)									
Control Input Low Voltage, V_{ILC} (Max.)	$ I_{IS} < 10 \mu\text{A}$ $V_{IS} = V_{SS}$, $V_{OS} = V_{DD}$ and $V_{IS} = V_{DD}$, $V_{OS} = V_{SS}$	5, 10, 15	0.9	0.9	0.4	0.4	—	0.7	V
Control Input High Voltage, V_{IHC}	See Fig. 10	5 10 15			3.5 (Min.)	7 (Min.)	11 (Min.)		V
Input Current, I_{IN} (Max.)	$V_{IS} \leq V_{DD}$ $V_{DD} - V_{SS} = 18 \text{ V}$ $V_{CC} \leq V_{DD} - V_{SS}$	18	± 0.1	± 0.1	± 1	± 1	$\pm 10^{-5}$	± 0.1	μA
Crosstalk (Control Input to Signal Output)	$V_C = 10 \text{ V}$ (Sq. Wave) $t_r, t_f = 20 \text{ ns}$ $R_L = 10 \text{ k}\Omega$	10	—	—	—	—	50		mV
Turn-On Propagation Delay	$t_r, t_f = 20 \text{ ns}$ $C_L = 50 \text{ pF}$ $R_L = 1 \text{ k}\Omega$	5 10 15	—	—	—	—	35 20 15	70 40 30	ns
Maximum Control Input Repetition Rate	$V_{IS} = V_{DD}$, $V_{SS} = \text{GND}$, $R_L = 1 \text{ k}\Omega$ to gnd, $C_L = 50 \text{ pF}$, $V_C = 10 \text{ V}$ (Square wave centered on 5 V) $t_r, t_f = 20 \text{ ns}$, $V_{OS} = \frac{1}{2} V_{OS}$ @ 1 kHz	10	—	—	—	—	10	—	MHz
Input Capacitance, C_{IN}			—	—	—	—	5	7.5	μF

V_{DD} (V)	V_{IS} (V)	Switch Input						Switch Output V_{OS} (V)	
		I_{IS} (mA)							
		-55°C	-40°C	25°C*	25°C▲	+85°C	+125°C		
5	0	0.25	0.2	0.2	0.16	0.12	0.14	—	0.4
5	5	-0.25	-0.2	-0.2	-0.16	-0.12	-0.14	4.6	—
10	0	0.62	0.5	0.5	0.4	0.3	0.35	—	0.5
10	10	-0.62	-0.5	-0.5	-0.4	-0.3	-0.35	9.5	—
15	0	1.8	1.4	1.5	1.2	1	1.1	—	1.5
15	15	-1.8	-1.4	-1.5	-1.2	-1	-1.1	13.5	—

* Plastic package

▲ Ceramic package

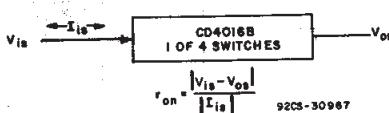


Fig. 10—Determination of r_{on} as a test condition for control input high voltage (V_{IHC}) specification.

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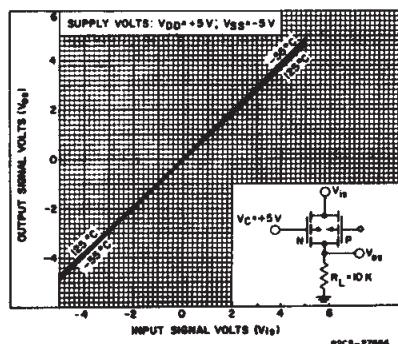


Fig. 7—Typ. on-state characteristics as a function of temp. for 1 of 4 switches with $V_{DD} = +5 \text{ V}$, $V_{SS} = -5 \text{ V}$.
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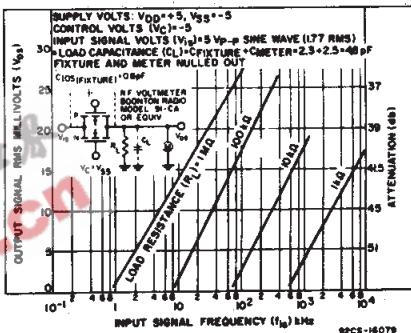


Fig. 8—Typ. feedthru vs. frequency — switch off.
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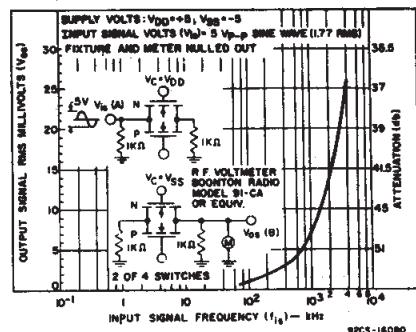


Fig. 9—Typical crosstalk between switch circuits in the same package.
92CS-16079

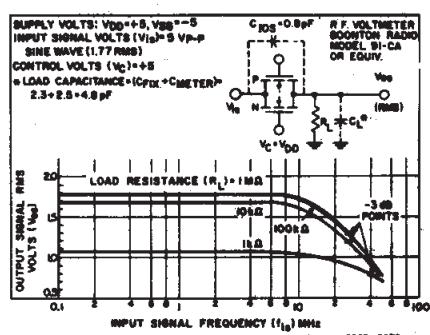


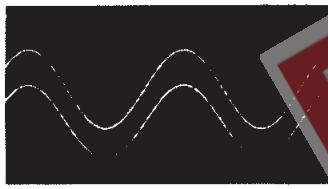
Fig. 11—Typical frequency response — switch on.
92CS-16079

CD4016B Types

TYPICAL ON-STATE RESISTANCE CHARACTERISTICS, $T_A = 25^\circ\text{C}$

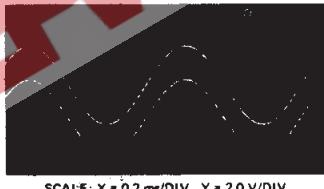
CHARACTERISTIC*	SUPPLY CONDITIONS		LOAD CONDITIONS					
			$R_L = 1\text{k}\Omega$		$R_L = 10\text{k}\Omega$		$R_L = 100\text{k}\Omega$	
	V_{DD} (V)	V_{SS} (V)	VALUE (Ω)	V_{IS} (V)	VALUE (Ω)	V_{IS} (V)	VALUE (Ω)	V_{IS} (V)
r_{on}	+15	0	200	+15	200	+15	180	+15
			200	0	200	0	200	0
r_{on} (max.)	+15	0	300	+11	300	+9.3	320	+9.2
			290	+10	250	+10	240	+10
r_{on}	+10	0	290	0	250	0	300	0
			290	+7.4	560	+5.6	610	+5.5
r_{on}	+5	0	860	+5	470	+5	450	+5
			600	0	580	0	800	0
r_{on} (max.)	+5	0	1.7k	+4.2	7k	+2.9	33k	+2.7
			200	+7.5	200	+7.5	180	+7.5
r_{on}	+7.5	-7.5	200	-7.5	200	-7.5	180	-7.5
			200	-7.5	200	-7.5	180	-7.5
r_{on} (max.)	+7.5	-7.5	290	± 0.25	280	± 0.25	400	± 0.25
			260	+5	250	+5	240	+5
r_{on}	+5	-5	310	-5	250	-5	240	-5
			600	± 0.25	580	± 0.25	760	± 0.25
r_{on}	+2.5	-2.5	590	+2.5	450	+2.5	490	+2.5
			720	-2.5	520	-2.5	520	-2.5
r_{on} (max.)	+2.5	-2.5	232k	± 0.25	300k	± 0.25	870k	± 0.25

* Variation from a perfect switch, $r_{on} = 0 \Omega$.



SCALE: X = 0.2 ms/DIV Y = 2.0 V/DIV
 $V_{DD} = V_C = +7.5\text{V}$, $V_{SS} = -7.5\text{V}$, $R_L = 10\text{k}\Omega$
 $C_L = 15\text{ pF}$
 $f_{IS} = 1\text{ KHz}$ $V_{IS} = 5\text{V pp}$
DISTORTION = 0.2 %

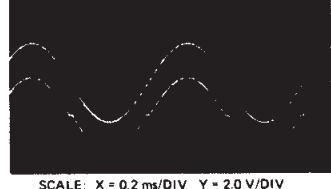
Fig.14 – Typical sine wave response of $V_{DD} = +7.5\text{V}$, $V_{SS} = -7.5\text{V}$.



SCALE: X = 0.2 ms/DIV Y = 2.0 V/DIV
 $V_{DD} = V_C = +5\text{V}$, $V_{SS} = -5\text{V}$, $R_L = 10\text{k}\Omega$
 $C_L = 15\text{ pF}$
 $f_{IS} = 1\text{ KHz}$ $V_{IS} = 5\text{V pp}$
DISTORTION = 0.4 %

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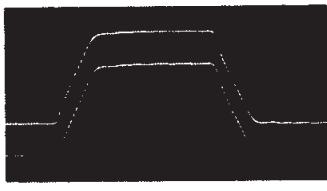
Fig.15 – Typical sine wave response of $V_{DD} = +5\text{V}$, $V_{SS} = -5\text{V}$.



SCALE: X = 0.2 ms/DIV Y = 2.0 V/DIV
 $V_{DD} = V_C = +2.5\text{V}$, $V_{SS} = -2.5\text{V}$, $R_L = 10\text{k}\Omega$
 $C_L = 15\text{ pF}$
 $f_{IS} = 1\text{ KHz}$ $V_{IS} = 5\text{V pp}$
DISTORTION = 0.3 %

92CS-27614

Fig.16 – Typical sine wave response of $V_{DD} = +2.5\text{V}$, $V_{SS} = -2.5\text{V}$.



SCALE: X = 100 ns/DIV Y = 5.0 V/DIV

92CS-27615

Fig.17 – Typical square wave response at $V_{DD} = V_C = +15\text{V}$, $V_{SS} = \text{Gnd}$.



SCALE: X = 100 ns/DIV Y = 5.0 V/DIV

92CS-27616

Fig.18 – Typical square wave response at $V_{DD} = V_C = +10\text{V}$, $V_{SS} = \text{Gnd}$.



SCALE: X = 100 ns/DIV Y = 2 V/DIV

92CS-27617

Fig.19 – Typical square wave response at $V_{DD} = V_C = +5\text{V}$, $V_{SS} = \text{Gnd}$.

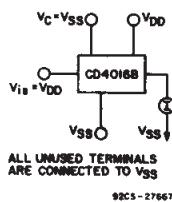


Fig. 12 – Off-state switch input or output leakage current test circuit.

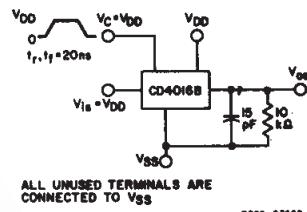
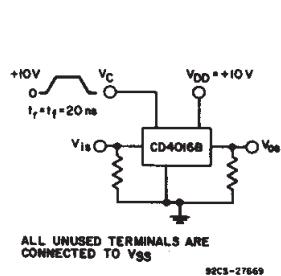


Fig.13 – Test circuit for square-wave response.

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(a)

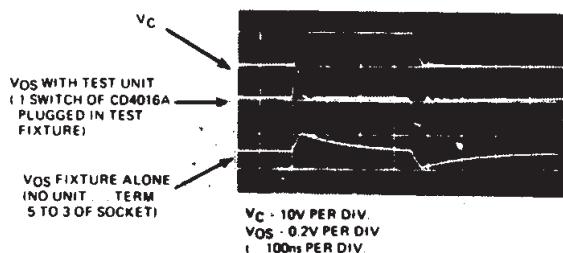


Fig. 20 — Crosstalk-control input to signal output.

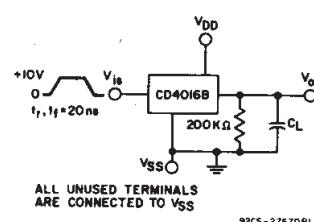


Fig. 21 — Propagation delay time signal input (V_{IS}) to signal output (V_{OS}).

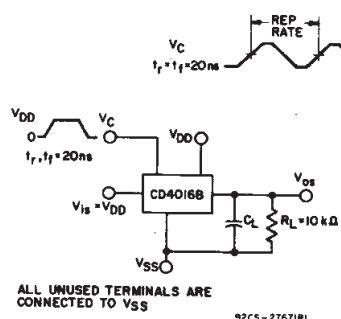


Fig. 22 — Max. control-input repetition rate.

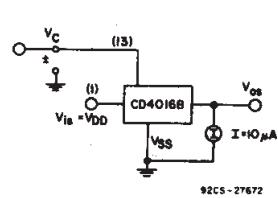


Fig. 23 — Switch threshold voltage.

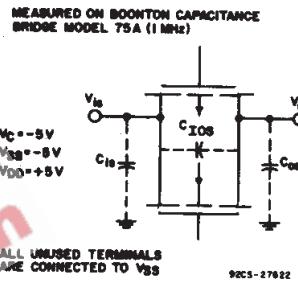


Fig. 24 — Capacitance C_{10S} and C_{0S}.

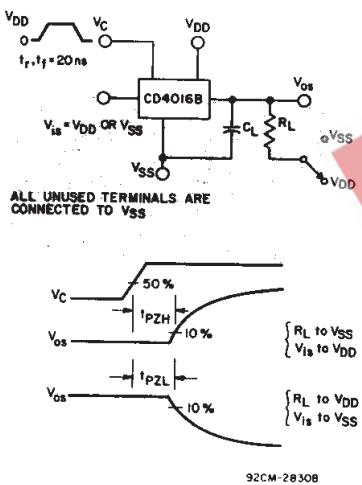
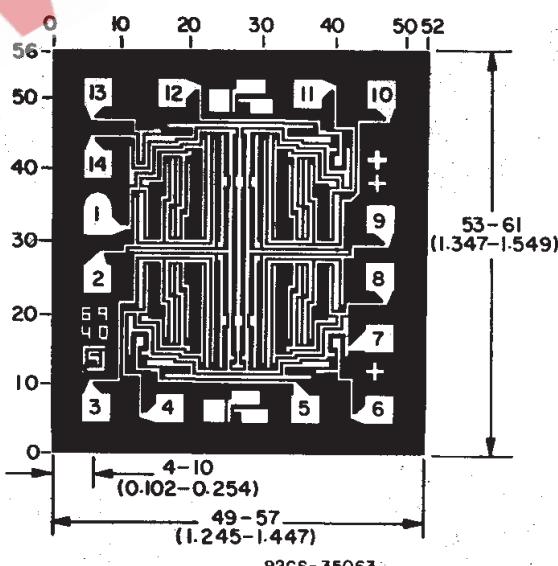


Fig. 25 — Turn-On propagation delay-control input.

Dimensions and pad layout for CD4016BH.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

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